

Zibo Seno Electronic Engineering Co., Ltd.



MURB1010CT-MURB1060CT



10.0A GLASS PASSIVATED SUPER FAST RECTIFIER

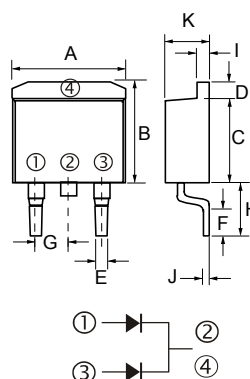
Features

- Glass Passivated Die Construction
- Super-Fast Switching
- Low Forward Voltage Drop
- Low Reverse Leakage Current
- High Surge Current Capability
- Plastic Material has UL Flammability Classification 94V-O

D² PAK/TO-263AB

Mechanical Data

- Case: TO-263AB(D²PAK), Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: See Diagram
- Mounting Position: Any
- **Lead Free: For RoHS / Lead Free Version**



D ² PAK/TO-263		
DIM.	MIN.	MAX.
A	9.80	10.20
B	9.60	10.60
C	8.50	9.20
D	----	1.67
E	0.51	1.01
F	2.10	2.50
G	2.44	2.64
H	4.40	4.70
I	1.10	1.40
J	0.30	0.64
K	4.40	4.80

All Dimensions in millimeter

Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

Characteristic	SYMBOL	MURB 1010CT	MURB 1020CT	MURB 1030CT	MURB 1040CT	MURB 1050CT	MURB 1060CT	UNIT
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	100	200	300	400	500	600	V
Maximum RMS Voltage	V _{RMS}	70	140	210	280	350	420	V
Maximum DC Blocking Voltage	V _{DC}	100	200	300	400	500	600	V
Maximum Average Forward Rectified Current T _c =100°C	I _{F(AV)}	10.0						A
Peak Forward Surge Current, 8.3ms single Half sine-wave superimposed on rated load (JEDEC method)	I _{FSM}	90						A
Maximum Instantaneous Forward Voltage @ 5.0 A	V _F	1.0		1.3		1.7		V
Maximum DC Reverse Current @T _J =25°C At Rated DC Blocking Voltage @T _J =125°C	I _R	5.0			250			uA uA
Maximum Reverse Recovery Time (Note 1)	T _{rr}	35						nS
Typical junction Capacitance (Note 2)	C _J	170			130			pF
Typical Thermal Resistance (Note 3)	R _{θJC}	3.5						°CW
Operating Junction and Storage Temperature Range	T _J , T _{STG}	-55 to +150						°C

Note: 1. Measured with I_F = 0.5A, I_R = 1.0A, I_{RR} = 0.25A.
2. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

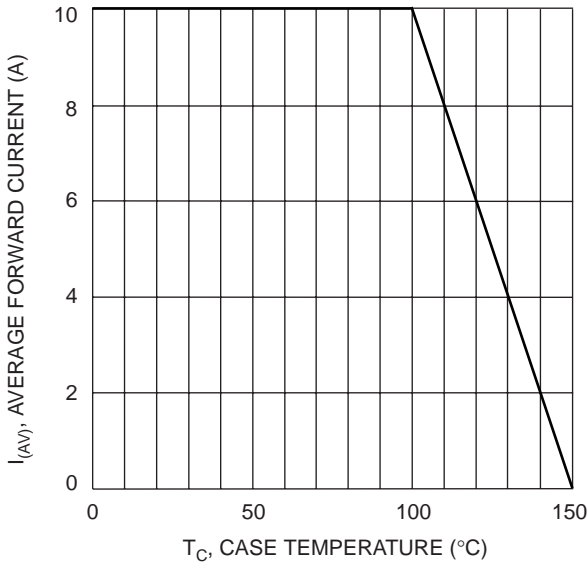


Fig. 1 Forward Current Derating Curve

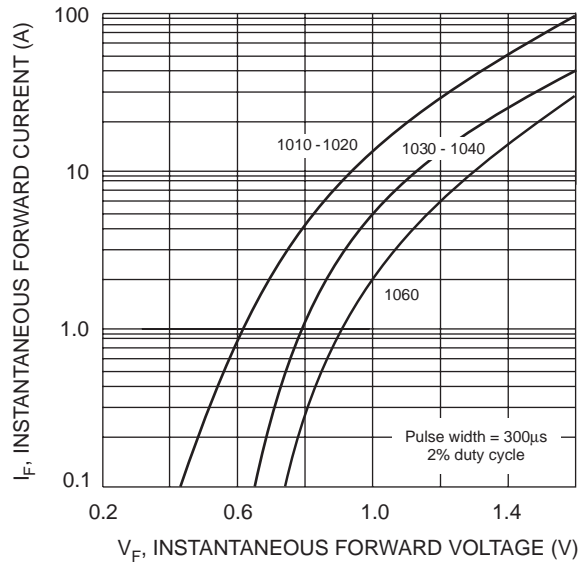


Fig. 2 Typical Forward Characteristics

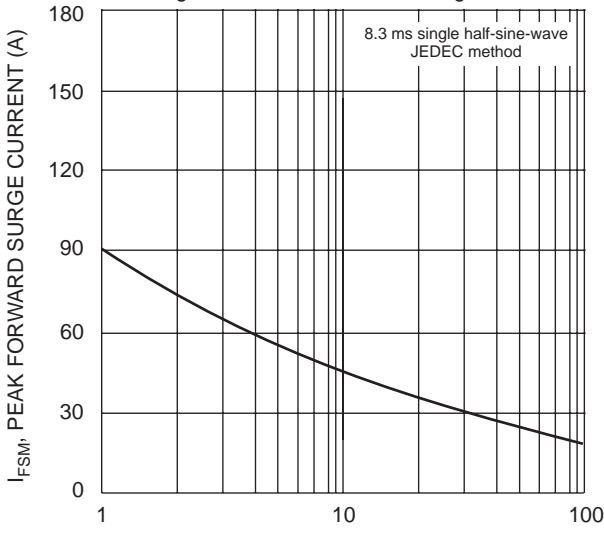


Fig. 3 Max Non-Repetitive Surge Current

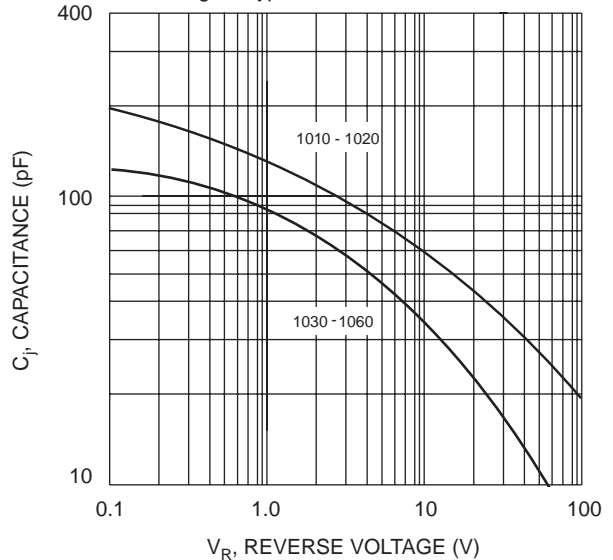
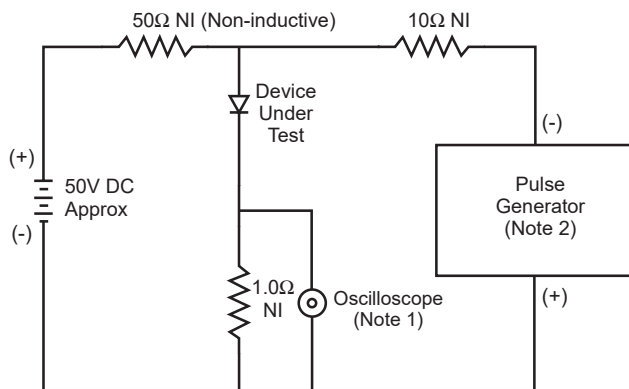
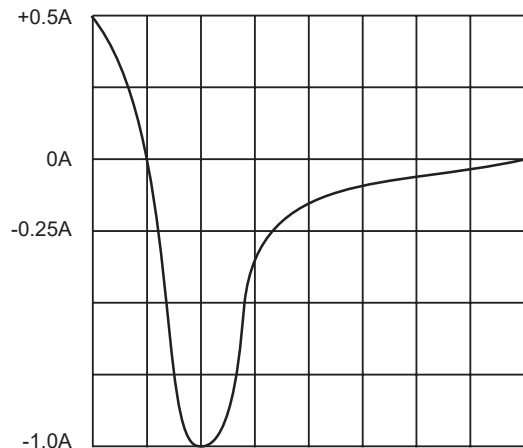


Fig. 4 Typical Junction Capacitance



- Notes:
1. Rise Time = 7.0ns max. Input Impedance = 1.0MΩ, 22pF.
 2. Rise Time = 10ns max. Input Impedance = 50Ω.



Set time base for 5/10ns/cm

Fig. 5 Reverse Recovery Time Characteristic and Test Circuit